## 3次元形状記憶素子の試作と形状回復動作の観察

純Ti線にNiメッキを施した線材をセラミックス製マンドレルに巻き付けて円筒形状を付与し、 減圧雰囲気にて1173Kで種々の時間の拡散熱処理を行った. 拡散熱処理後の試料にたい して行ったX線回折試験及び走査電顕観察から、TiNi形状記憶合金相が得られていること が明らかになった. 示差走査熱量測定では、熱弾性型マルテンサイト変態を示す発熱ピー ク及び吸熱ピークが明瞭に観察された. 1173K-28.8ksの拡散熱処理した円筒状試料を室温 にて形状変形し外部熱源によって加熱したところ、典型的な形状回復動作を示した.

20 sec 30 sec 10 sec 40 sec A Ni-coated Ti wire, which was seamless and continuous one, was used. The wire with 125  $\mu m$ diameter was cold-rolled. 0 sec Before Rolling After Rolling 20mm 50μm 50μm Heat-treated at Ni Layer The cold-rolled wire was wound several times on to a cylyndrical mandrel. in vacuum.

Fig.: NiメッキしたTi線を用いたTiNi形状記憶素子の製造方法

Fig.: 1173K-28.8ksの拡散熱処理で得た素子の形状回復動作. 453Kに保持した加熱装置状に素子を設置して形状回復動作を観察.

## Propose a New Fabrication Technique for a 3-Dimensional TiNi devices

A new fabrication technique for a TiNi tube-like device via a Ni-coated Ti wire was proposed. The Ni-coated Ti wire was wound on to a cylindrical mandrel. A subsequent heat-treatment, which was heated at 1173 K for various times in vacuum, was carried out. Observations of X-ray diffractometry and scanning electron microscopy show that TiNi compounds formed in the heat-treated devices. An endothermic peak and an exothermic peak in differential scanning calorimetry diagram were observed on the heating and cooling process, respectively. The device heat-treated at 1173K for 28.8ks demonstrates a good shape memory motion.

A Ni-coated Ti wire, which was seamless and continuous one, was used. The wire with 125 µm diameter was cold-rolled.

Before Rolling

12 µm

Ni Layer

Ni Layer

After Rolling

After Rolling

Heat-treated at 1178 K for several times in vacuum.

Fig.: Producing procedure for a TiNi tube-like device via a Ni-coated Ti wire.

Fig.: Shape recovery motion of a tube-like device heat-treated at 1173K for 28.8ks. The device was set on an electric heating plate kept at 453K.

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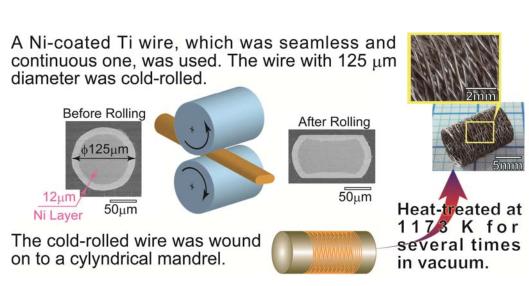


Fig.: Producing procedure for a TiNi tube-like device via a Ni-coated Ti wire.

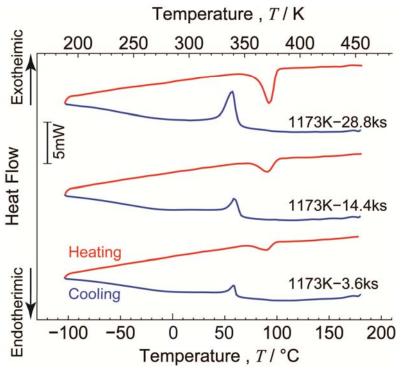


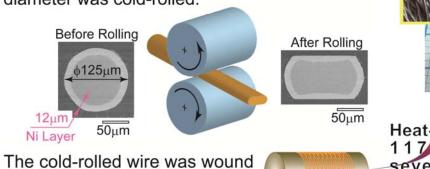
Fig.: DSC curves of Ni-coated Ti wires heat-treated at 1173K for 3.6ks, 14.4ks and 28.8ks.

## 3次元形状記憶素子の製造法の提案

純Ti線にNiメッキを施した線材をセラミックス製マンドレルに巻き付けて円筒形状を付与し た後,減圧雰囲気にて1173Kで種々の時間の拡散熱処理を行った.拡散熱処理後の試 料にたいして行ったX線回折試験及び走査電顕観察から, TiNi形状記憶合金相が得られ ていることが明らかになった. 示差走査熱量計では, 熱弾性型マルテンサイト変態を示す 発熱ピーク及び吸熱ピークが明瞭に観察されたので、3次元形状の形状記憶合金素子と して機能することが期待できる.

(特許出願中)

A Ni-coated Ti wire, which was seamless and continuous one, was used. The wire with 125 µm diameter was cold-rolled.



on to a cylyndrical mandrel.

Heat-treated at 1178 K for several times in vacuum.

Fig.: NiメッキしたTi線を用いたTiNi形状記憶素子の製造方法

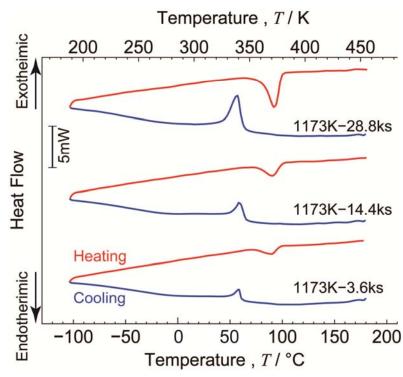


Fig.: 拡散熱処理で得た素子の変態点測定結果. 典型 的な発熱ピークと吸熱ピークが得られたので、形状記憶 特性が付与されていることがわかる.